Vishay Semiconductors

High Performance Schottky Rectifier, 20 A



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PRIMARY CHARACTERISTICS				
I _{F(AV)} 20 A				
V _R	15 V			
V _F at I _F	See Electrical table			
I _{RM} max.	600 mA at 100 °C			
T _J max.	125 °C			
E _{AS}	10 mJ			
Package	TO-220AC 2L			
Circuit configuration	Single			

FEATURES

- 125 °C T_J operation ($V_R < 5 V$)
- Optimized for OR-ing applications
- Ultra low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Designed and qualified according to JEDEC[®]-JESD47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL CHARACTERISTICS VALUES U					
I _{F(AV)}	Rectangular waveform	20	А		
V _{RRM}		15	V		
I _{FSM}	$t_p = 5 \ \mu s$ sine	700	А		
V _F	19 A _{pk} , T _J = 125 °C (typical)	0.25	V		
TJ	Range	-55 to +125	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-STPS20L15D-M3	UNITS		
Maximum DC reverse voltage	V _R	15	V		
Maximum working peak reverse voltage	V _{RWM}	15	v		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle, $T_C = 85 \ ^\circ C$, r	20	А			
Maximum peak one cycle non-repetitive surge current	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	700	A		
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 6 mH		10	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to ze Frequency limited by T _J maxin	2	А			

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VS-STPS20L15D-M3



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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS	
		19 A	T.I = 25 °C	-	0.41		
Forward voltage drop	V _{FM} ⁽¹⁾	40 A	1j=25 0	-	0.52	v	
See fig. 1	V FM (**	19 A	T.I = 125 °C	0.25	0.33	v	
		40 A	1j = 125 C	0.37	0.50		
Reverse leakage current	I _{BM} ⁽¹⁾	$T_J = 25 \text{ °C}$		-	10	mA	
See fig. 2	IRM \''	T _J = 100 °C	$V_R = Rated V_R$	-	600	ma	
Threshold voltage	V _{F(TO)}			0.1	82	V	
Forward slope resistance	r _t	$I_{J} = I_{J} maximum$	$T_{J} = T_{J} maximum$.6	mΩ	
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal rar	-	2000	pF		
Typical series inductance	L _S	Measured lead to lead 5	8	-	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10	000	V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	TJ		-55 to +125	С°		
Maximum storage temperature range	T _{Stg}		-55 to +150			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.5			
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50	°C/W		
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (for D ² PAK)	40			
Approvimate weight			2	g		
Approximate weight			0.07	oz.		
Mounting torque		Non-lubricated threads	6 (5)	kgf ⋅ cm		
Mounting torque maximum		Non-Iudiicaleu lineaus	12 (10)	(lbf ⋅ in)		
Marking device		Case style TO-220AC 2L	STPS2	0L15D		



VS-STPS20L15D-M3

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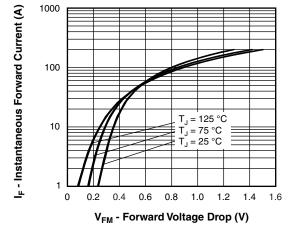


Fig. 1 - Maximum Forward Voltage Drop Characteristics

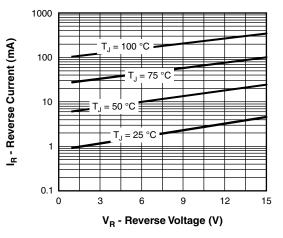


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

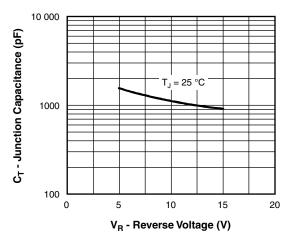


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

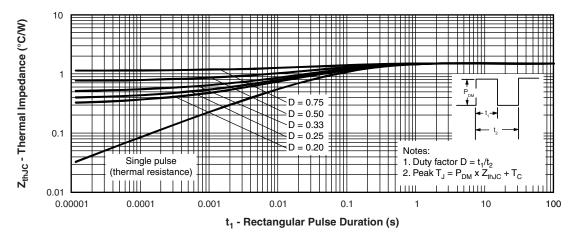
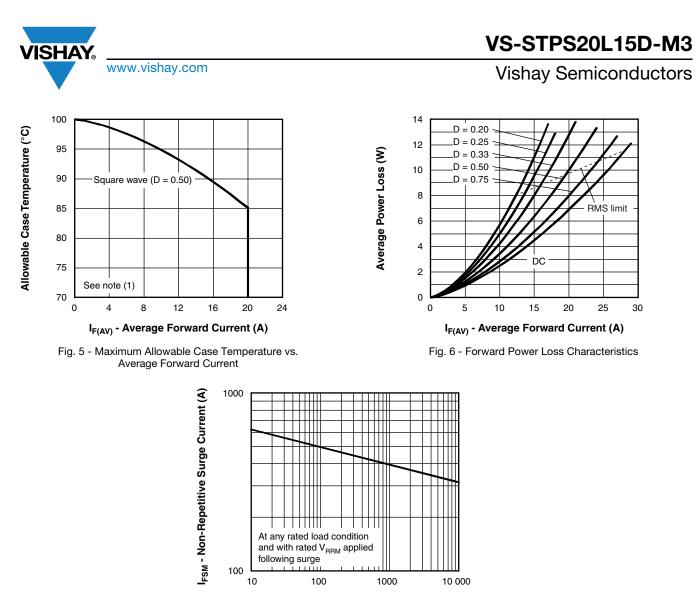


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

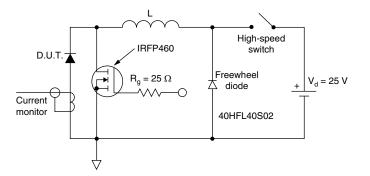
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t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current





Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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Device

ORDERING INFORMATION TABLE

code	vs-	STPS	20	L	15	D	-M3
	1	2	3	4	5	6	7
	1 -	Vish	ay Sem	niconduc	tors pro	duct	
	2 -	Sch	ottky ST	PS seri	es		
	3 -	Curi	rent ratii	ng (20 =	20 A)		
	4 -	L =	Low vol	tage dro	р		
	5 -	Volt	age ratii	ng (15 =	= 15 V)		
	6 -	D =	Essenti	al part n	umber		
	7 -	Env	ironmer	ntal digit			
		-M3	= haloc	non_froo	RoHS-	compliar	t and t

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION					
VS-STPS20L15D-M3	50	Antistatic plastic tubes			

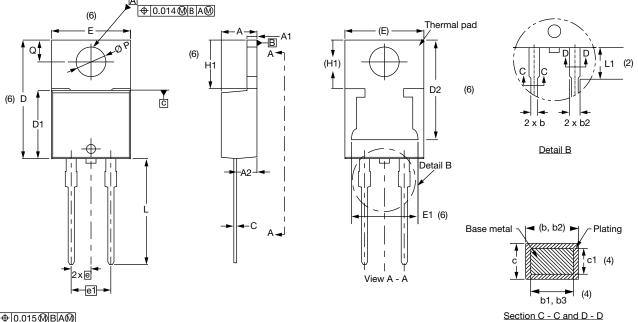
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96156			
Part marking information	www.vishay.com/doc?95391			
SPICE model	www.vishay.com/doc?95305			



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TO-220AC 2L

DIMENSIONS in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INCHES		NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

Conforms to JEDEC	® outline TO-220AC

SYMBOL	MILLIMETERS		INCHES		NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	11.68	13.30	0.460	0.524	6, 7	
E	10.11	10.51	0.398	0.414	3, 6	
E1	6.86	8.89	0.270	0.350	6	
е	2.41	2.67	0.095	0.105		
e1	4.88	5.28	0.192	0.208		
H1	6.09	6.48	0.240	0.255	6	
L	13.52	14.02	0.532	0.552		
L1	3.32	3.82	0.131	0.150	2	
ØР	3.54	3.91	0.139	0.154		
Q	2.60	3.00	0.102	0.118		

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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